2SJ652-1E Information

Part Number	2SJ652-1E
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Description	MOSFET P-CH 60V 28A TO-220FP-3
Package	TO-220-3 Full Pack

For Reference Only

For the pricing/inventory/lead time, please contact us
Website: https://www.heisener.com
E-mail: salesdept@heisener.com

Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.

2SJ652-1E Specifications

Manufacturer Part Number	2SJ652-1E
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-220-3 Full Pack
Series	-
FET Type	P-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	60V
Current - Continuous Drain (Id) @ 25°C	28A (Ta)
Drive Voltage (Max Rds On, Min Rds On)	4V, 10V
Vgs(th) (Max) @ Id	-
Gate Charge (Qg) (Max) @ Vgs	80nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	4360pF @ 20V
Vgs (Max)	±20V
FET Feature	-
Power Dissipation (Max)	2W (Ta), 30W (Tc)
Rds On (Max) @ Id, Vgs	38 mOhm @ 14A, 10V
Operating Temperature	150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-220F-3SG
Package / Case	TO-220-3 Full Pack
	Report errors?

2SJ652-1E Guarantees

Quality Guarantees
We provide 90 days warranty. *
If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

Service Guarantees
We guarantee 100% customer satisfaction.
Our experienced sales team and tech support team back our services to satisfy all our customers.

2SJ652-1E Payment Methods

2SJ652-1E Shipping Methods

If you have any question about 2SJ652-1E, please do not hesitate to contact us!
Website: https://www.heisener.com
E-mail: salesdept@heisener.com